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UNIVERSITI TUN HUSSEIN ONN MALAYSIA

FINAL EXAMINATION
SEMESTER I
SESSION 2016/2017

COURSE NAME : ELECTRONIC PRINCIPLES
COURSE CODE : BNR20503
PROGRAMME CODE : 2BND / BNF
EXAMINATION DATE : DECEMBER 2016 / JANUARY 2017
DURATION : 2 HOURS 30 MINUTES
INSTRUCTION : ANSWERS **FOUR (4)** QUESTIONS ONLY

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THIS QUESTION PAPER CONSISTS OF NINE (9) PAGES

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- Q1** (a) Briefly define the following terms with the aid of diagram for both forward bias and reverse bias connection. :
- (i) Ideal diode model (3 marks)
 - (ii) Practical diode model (3 marks)
- (b) Sketch V_O for the network in **Figure Q1 (b)**. Determine the dc voltage available. Assume all the diodes are ideal. Show all calculations. (6 marks)
- (c) Draw and completely label the output waveform, V_O for the circuit shown in **Figure Q1(c)**. Assume all the diodes are silicon. Show all your steps in obtaining the waveforms. (5 marks)
- (d) **Figure Q1 (d)** shows the Zener diode circuit. Given, P_{ZM} (maximum power) = 40 mW. Assume the Zener diode is ideal. Determine:
- (i) the output voltage, V_o (2 marks)
 - (ii) voltage drop across load, V_{RL} (2 marks)
 - (iii) zener current, I_z (2marks)
 - (iv) power dissipated by the zener diode, P_z (2 marks)
- Q2** (a) A bipolar junction transistor (BJT) needs to be biased for it to operate.
- (i) How must the transistor junctions be biased for proper amplifier operation? (2 marks)
 - (ii) Describe the three modes of operation of a BJT. (6 marks)
- (b) The emitter-stabilized bias configuration of **Figure Q2 (b)** has the following specifications:
- $I_{CQ} = \frac{1}{2} I_{C(sat)}$, $I_{C(sat)} = 3.6$ mA, $V_E = 2.65$ V, $V_{CC} = 20$ V and $\beta = 50$.
- (i) Determine the values for R_C , R_E and R_B . (8 marks)

(ii) Draw the small-signal equivalent (AC equivalent) circuit for the circuit in **Figure Q2 (b)**.

(3 marks)

(iii) Calculate the values for input impedance (Z_i), output impedance (Z_o) and voltage gain (A_v).

(6 marks)

Q3 (a) Draw clearly the transfer characteristics curve of a JFET, D-MOSFET and an E-MOSFET. Describe the differences between them.

(9 marks)

(b) **Figure Q3 (b) (i)** shows a voltage divider bias FET circuit. Find the required values for R_S and R_D if the FET transfer characteristics curve with the defined Q-point is as shown in **Figure Q3 (b) (ii)** and the following values are given:

$$V_{DD} = 16 \text{ V}, R_1 = 2.1 \text{ M}\Omega \text{ and } R_2 = 270 \text{ k}\Omega, V_{DS} = 7 \text{ V}.$$

(8 marks)

(c) Find the input impedance (Z_i), output impedance (Z_o) and the output voltage of the amplifier in **Q3 (b)** if the input signal $V_i = 2 \text{ mV}$ (peak) and the ac output impedance $r_d = \infty$.

(8 marks)

Q4 For the network of **Figure Q4**, given $k = 0.6 \text{ mA/V}^2$, and $V_{GS(th)} = 4\text{V}$.

(a) Determine the I_{DQ} , V_{GSQ} , V_{DS} , V_G , V_D and V_S .

(14 marks)

(b) Draw the AC equivalent circuit. Determine the input impedance, Z_i and the output impedance, Z_o .

(7 marks)

(c) Find the mid-band frequency voltage gain, $A_v = V_o/V_i$.

(4 marks)

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Q5 For the network of **Figure Q5**:

- (a) Determine the ac resistance, r_e . Assume $V_{BE} = 0.7V$. (5 marks)
- (b) Draw the AC equivalent circuit and determine the input impedance, Z_i . (4 marks)
- (c) Find the mid-band frequency voltage gain $A_v = V_o/V_i$. (2 marks)
- (d) Find the voltage gain $A_{vs} = V_o/V_s$. (2 marks)
- (e) Determine the low cut-off frequencies, f_{Ls} , f_{LC} and f_{LE} . (6 marks)
- (f) Determine the high cut-off frequencies, f_{Hi} and f_{Ho} . (6 marks)

Q6 (a) For the Darlington pair circuit in **Figure Q6 (a)**, given $\beta_D = 6000$ and $V_{BE} = 1.6 V$.

- (i) Calculate the dc bias voltage, V_{E2} and emitter current, I_{E2} . (6 marks)
- (ii) Determine the output voltage. (4 marks)

(b) **Figure Q6 (b)** shows a differential amplifier with constant current source. Assuming that all transistors have $V_{BE} = 0.7V$, determine:

- (i) The current I . (4 marks)
- (ii) The common mode gain (4 marks)
- (iii) The differential gain (4 marks)
- (iv) The common-mode rejection ratio (CMRR) in dB . (3 marks)

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- END OF QUESTION -

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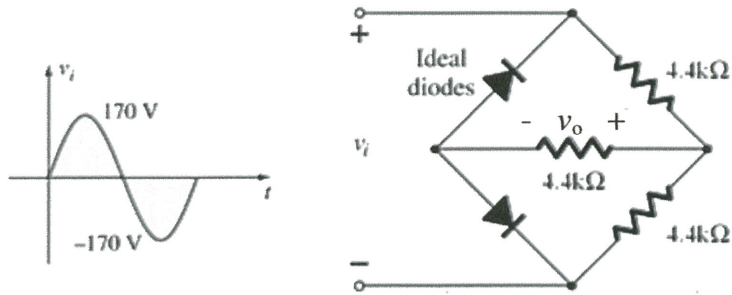


FIGURE Q1 (b)

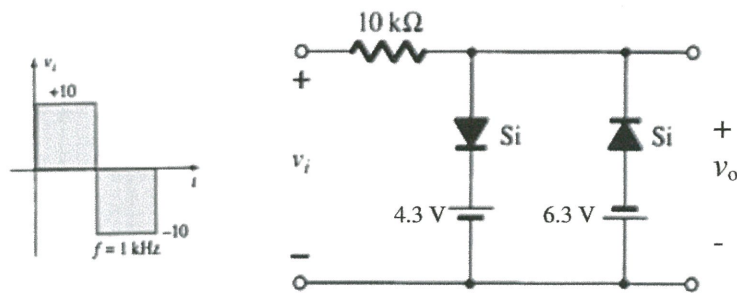
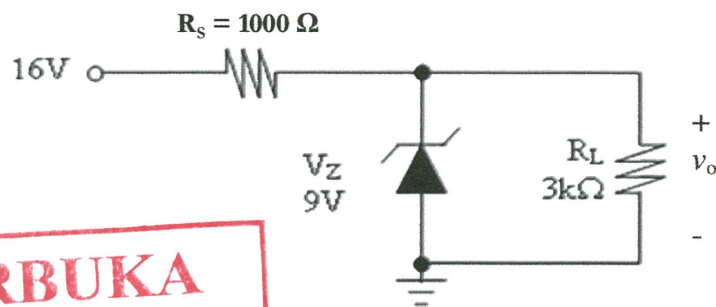


FIGURE Q1 (c)



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FIGURE Q1 (d)

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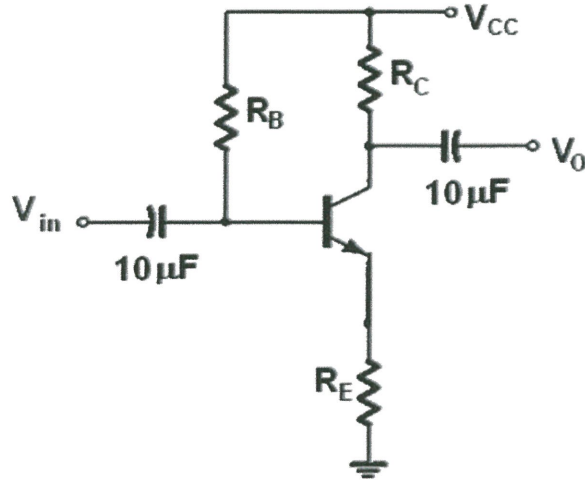


FIGURE Q2(c)

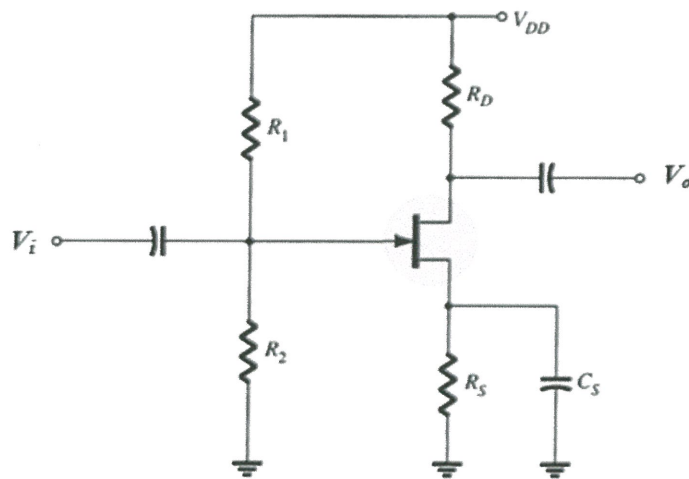


FIGURE Q3(b)(i)

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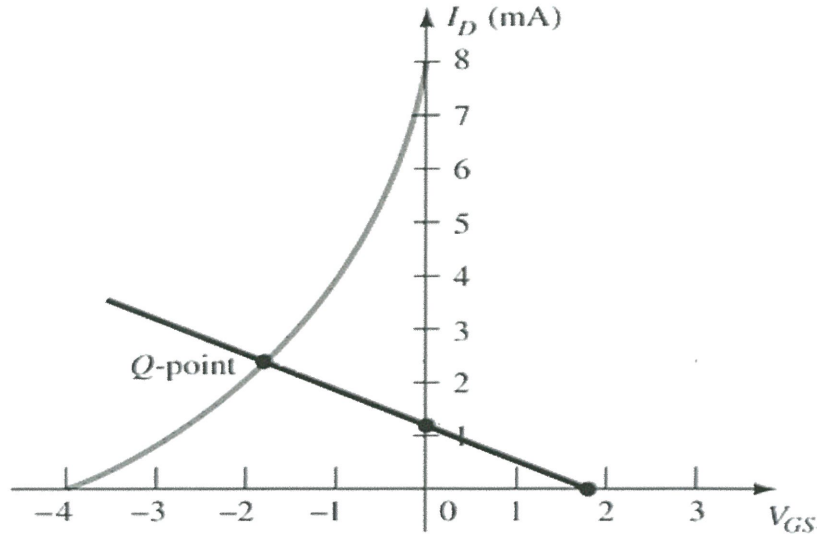
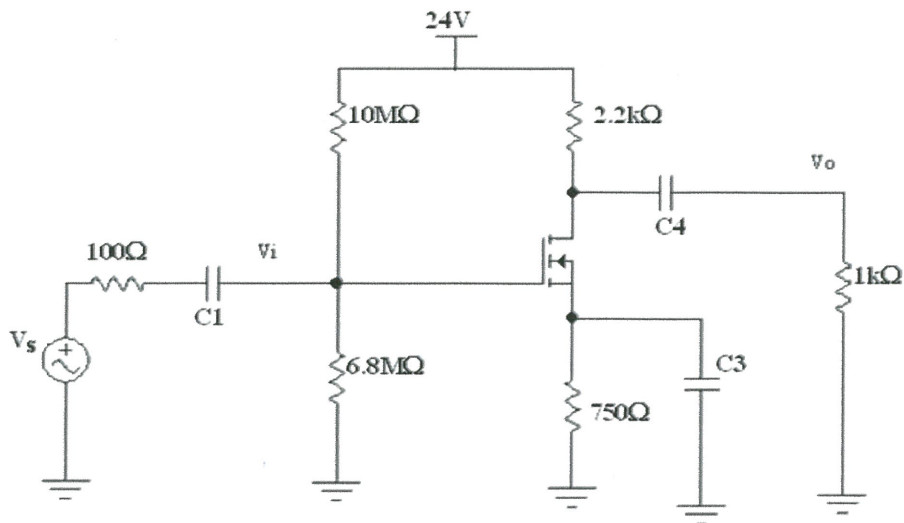


FIGURE Q3 (b)(ii)



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FIGURE Q4

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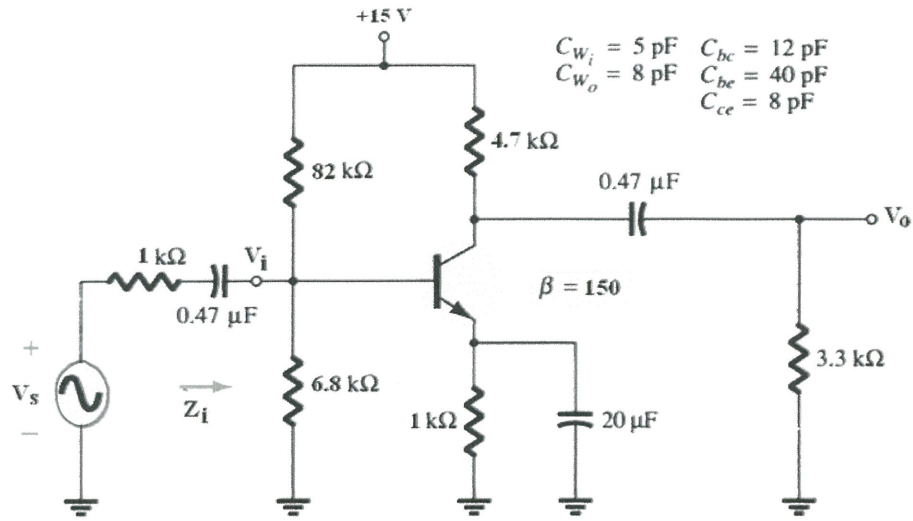
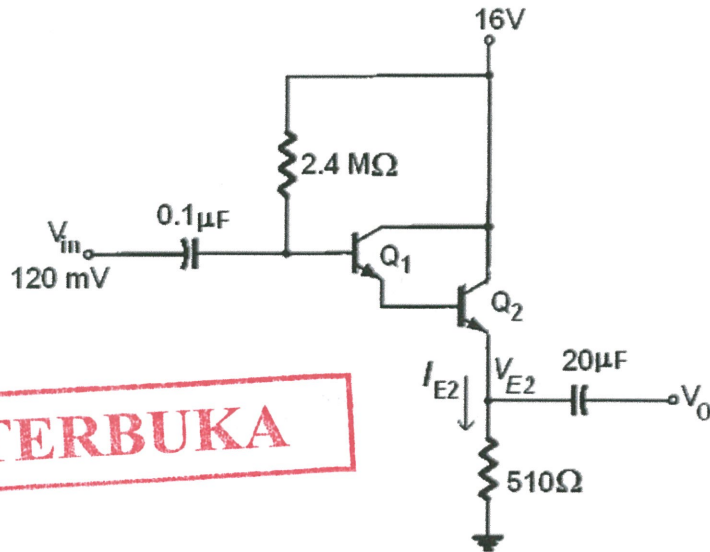


FIGURE Q5



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FIGURE Q6 (a)

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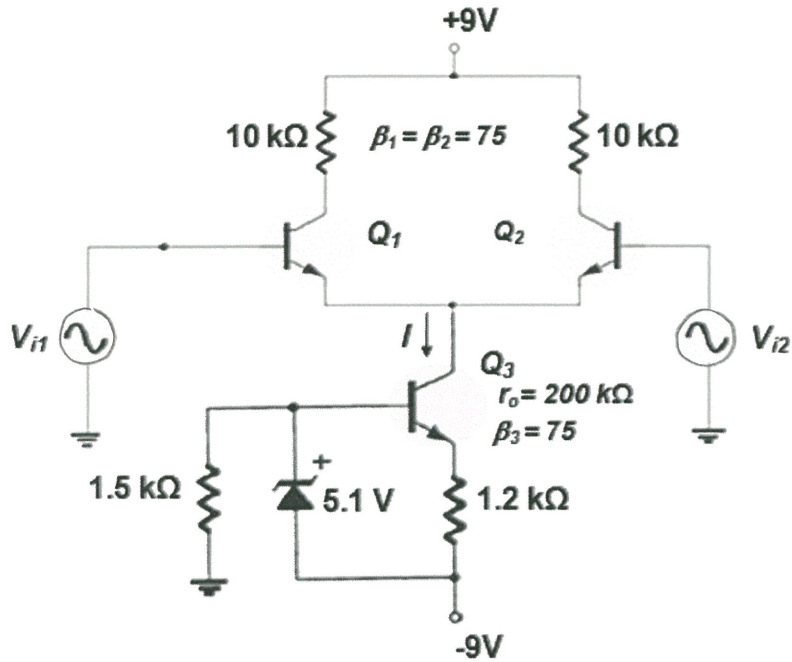


FIGURE Q6 (b)

List of formula:

$$k = \frac{I_{D(on)}}{(V_{GS(on)} - V_{GS(th)})^2}$$

$$R'_s = R_s \parallel R_1 \parallel R_2$$

$$g_m = 2k(V_{GS_0} - V_{GS(th)})$$

$$R_e = R_E \parallel \left(\frac{R'_s}{\beta} + r_e \right)$$

$$g_m = \frac{2I_{DSS}}{|V_P|} \left(1 - \frac{V_{GS}}{V_P} \right)$$

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